

N-Channel Enhancement Mode MOSFET

1. Product Information

1.1 Features

- ☒ Surface-mounted package
- ☒ Advanced trench cell design

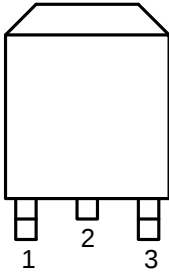
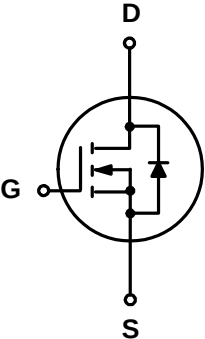
1.2 Applications

- ☒ BMS appliances
- ☒ High power inverter system
- ☒ Power Tool appliances

1.3 Quick reference

- ☒ $BV \geq 68\text{ V}$
- ☒ $P_{tot} \leq 110\text{ W}$
- ☒ $I_D \leq 80\text{ A}$
- ☒ $R_{DS(ON)} \leq 8\text{ m}\Omega @ V_{GS} = 10\text{ V}$

2. Pin Description

Pin	Description	Simplified Outline	Symbol
1	Gate(G)	 Top View TO-252	
2	Drain(D)		
3	Source(S)		

3. Limiting Values

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	Drain-Source Voltage	$T_C = 25\text{ }^{\circ}\text{C}$	68	-	V
V_{GS}	Gate-Source Voltage	$T_C = 25\text{ }^{\circ}\text{C}$	-	± 20	V
I_D^{***}	Drain Current (DC)	$T_C = 25\text{ }^{\circ}\text{C}, V_{GS} = 10\text{ V}$	-	80	A
		$T_C = 100\text{ }^{\circ}\text{C}, V_{GS} = 10\text{ V}$	-	68	A
I_{DM}^{****}	Drain Current (Pulsed)	$T_C = 25\text{ }^{\circ}\text{C}, V_{GS} = 10\text{ V}$	-	320	A
P_{tot}	Drain power dissipation	$T_C = 25\text{ }^{\circ}\text{C}$	-	110	W
T_{stg}	Storage Temperature		-55	150	$^{\circ}\text{C}$
T_J	Junction Temperature		-	150	$^{\circ}\text{C}$
I_S	Continuous-Source Current	$T_C = 25\text{ }^{\circ}\text{C}$	-	80	A
E_{AS}	Single Pulsed Avalanche Energy	$L=0.5\text{mH}, I_{as}=30\text{A}, T_J=25^{\circ}\text{C}$		390	mJ
$R_{\theta JA}^{**}$	Thermal Resistance- Junction to Ambient		-	62.5	$^{\circ}\text{C/W}$
$R_{\theta JC}^{**}$	Thermal Resistance- Junction to Case		-	1.36	

Notes :

- * Pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$
- ** Mounted on Large Heat Sink
- *** limited by bonding wire

4. Marking Information

Product Name	Marking
KJ6880K	6880K YWWXXX YWW: Date Code

5. Ordering Code

Product Name	Package	Reel Size	Tape width	Quantity	Note
KJ6880K	TO-252			2500	

Note: KJX defines “ Green ” as lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900 ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500 ppm by weight; Follow IEC 61249-2-21 and IPC / JEDEC J-STD-020C)

6. Electrical Characteristics ($T_A=25^\circ$ Unless Otherwise Noted)

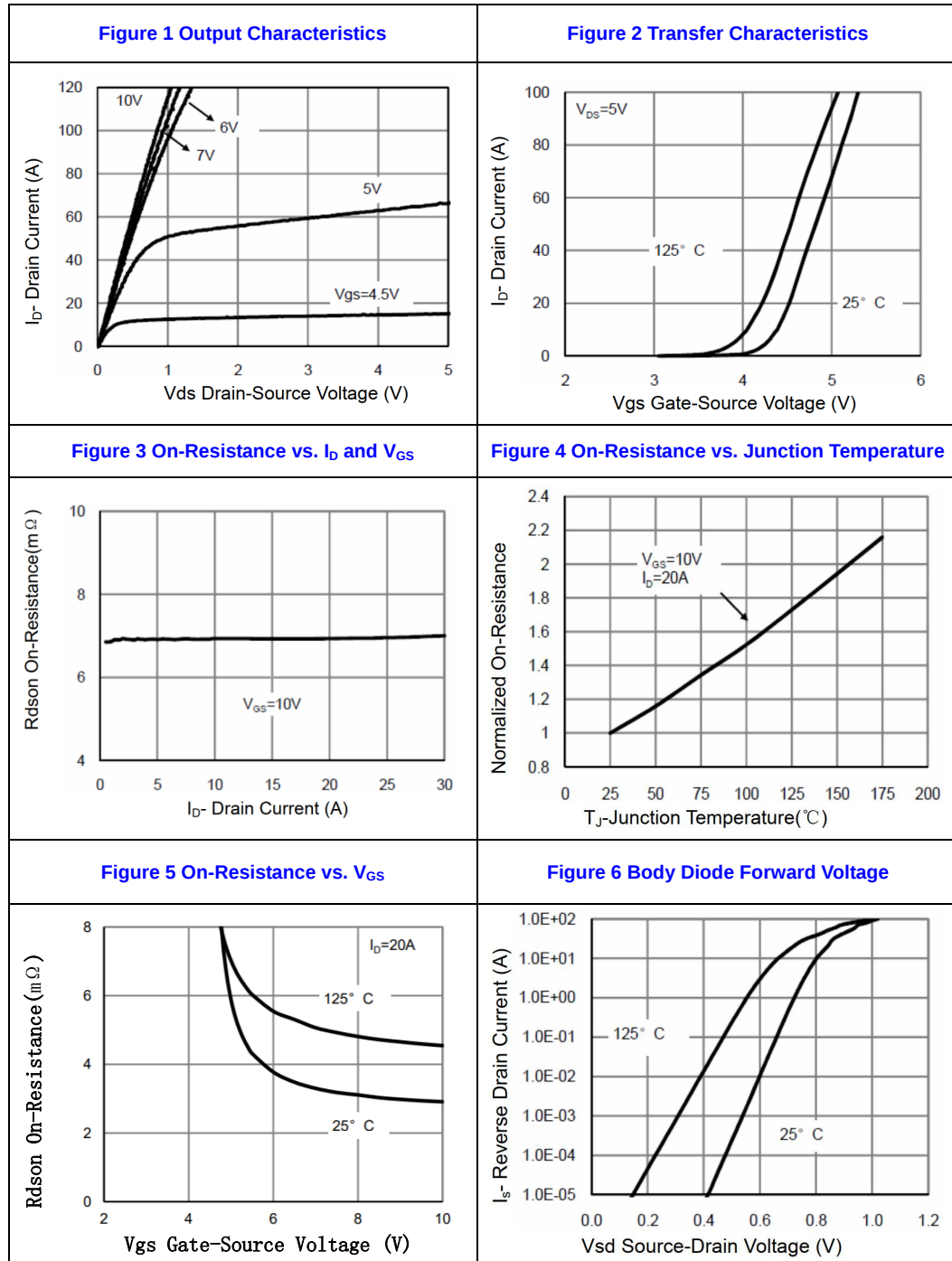
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static Characteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0 V, I _{DS} = 250 μA	68	-	-	V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} , I _{DS} = 250 μA	2.0	-	4.0	V
I _{DSS}	Drain Leakage Current	V _{DS} = 60 V, V _{GS} = 0 V	-	-	1	μA
I _{GSS}	Gate Leakage Current	V _{GS} = 0 V, V _{GS} = ± 20 V	-	-	±100	nA
R _{DS(ON)} ^a	On-State Resistance	V _{GS} = 10 V, I _{DS} = 20 A	-	7	8	mΩ
Diode Characteristics						
V _{SD} ^a	Diode Forward Voltage	I _{SD} = 20 A, V _{GS} = 0 V	-	-	1.2	V
Dynamic Characteristics ^b						
C _{iSS}	Input Capacitance	V _{GS} = 0 V, V _{DS} = 30 V Frequency = 1 MHz	-	4000	-	pF
C _{oSS}	Output Capacitance		-	290	-	
C _{rSS}	Reverse Transfer Capacitance		-	210	-	
t _{d(on)}	Turn-on Delay Time	V _{DS} = 30 V, V _{GEN} = 10 V, R _G = 4.5 Ω, R _L = 1.5 Ω, I _{DS} = 20 A	-	8.5	-	ns
t _r	Turn-on Rise Time		-	7	-	
t _{d(off)}	Turn-off Delay Time		-	40	-	
t _f	Turn-off Fall Time		-	15	-	
Gate Charge Characteristics ^b						
Q _g	Total Gate Charge	V _{DS} = 30 V, V _{GS} = 10 V, I _{DS} = 20 A	-	90	-	nC
Q _{gs}	Gate-Source Charge		-	9	-	
Q _{gd}	Gate-Drain Charge		-	18	-	

Notes :

a : Pulse test ; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$

b : Guaranteed by design, not subject to production testing

7. Typical Characteristics



7. Typical Characteristics (cont.)

Figure 7 Gate-Charge Characteristics

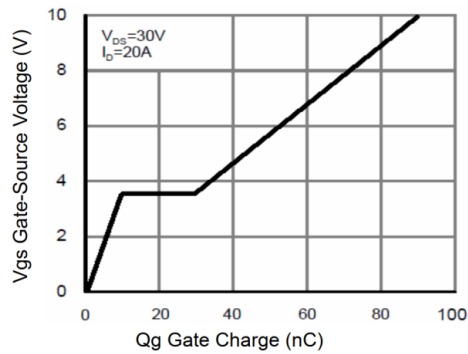


Figure 8 Capacitance Characteristics

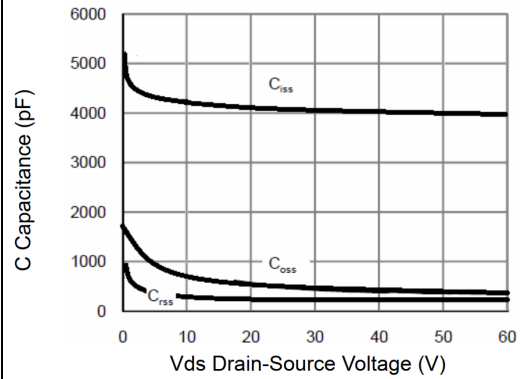


Figure 9a Maximum Forward Biased Safe

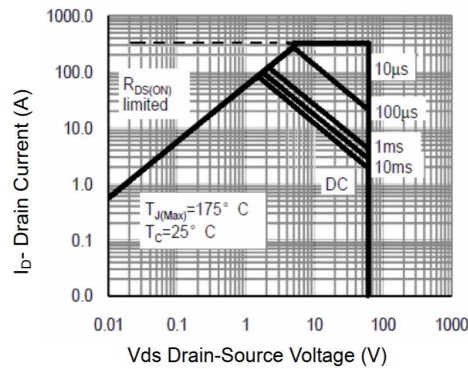


Figure 10a Single Pulse Power Rating

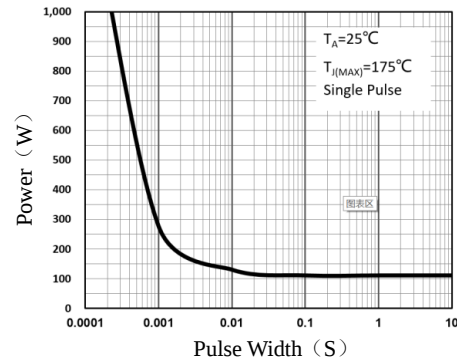
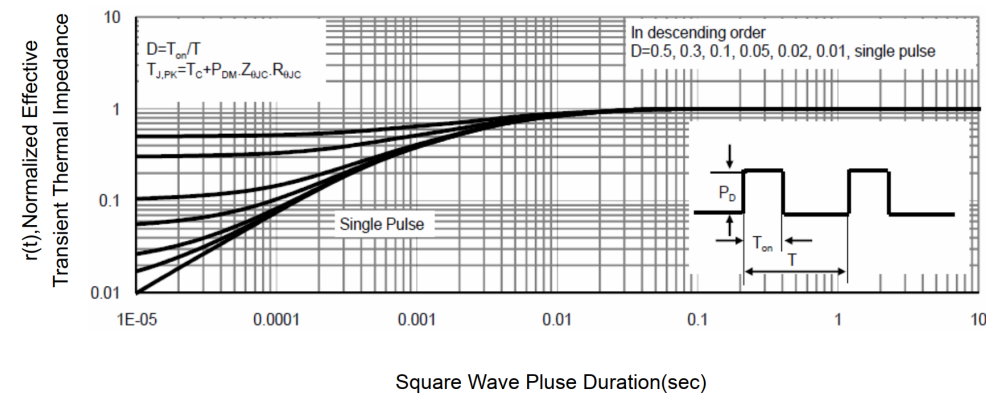
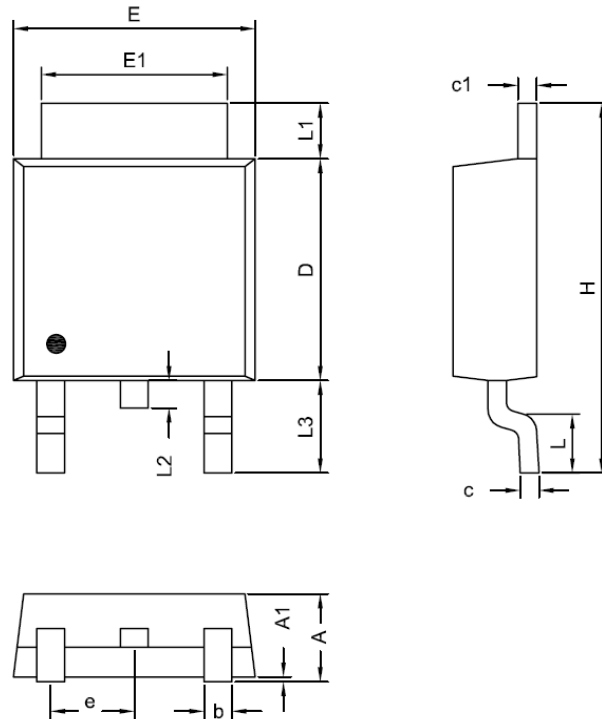


Figure 11a Normalized Maximum Transient Thermal Impedance



8.Package Dimensions

TO252-3L



Symbol	Dimensions In Millimeters	
	MIN.	MAX.
A	2.19	2.38
A1	0.02	0.13
D	5.30	6.40
E	6.35	6.80
E1	5.20	5.50
c	0.40	0.60
c1	0.40	0.60
b	0.55	0.85
e	2.30 BCS	
L	1.00	1.80
L1	0.70	1.80
L2	0.70 BCS	
L3	2.40	2.80
H	9.20	10.40